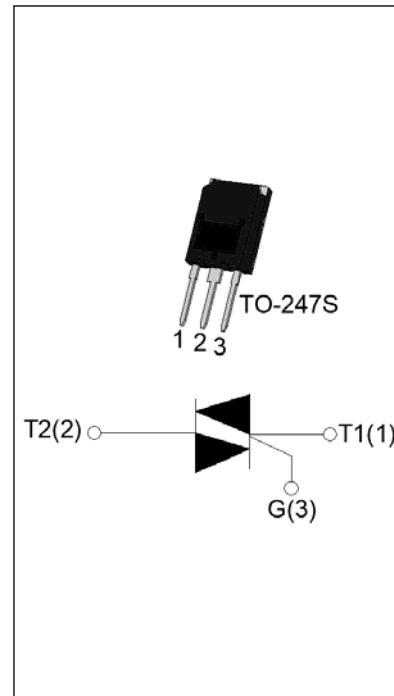


**DESCRIPTION:**

The JST60CS-1600BW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST60CS-1600BW snubberless triac is especially recommended for use on inductive loads. Package TO-247S is RoHS compliant.

**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	60	A
V_{DRM}/V_{RRM}	1600	V
$I_{GT\text{ I/II/III}}$	50/50/50	mA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	°C
Operating junction temperature range	T_j	-40-125	°C
Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$)	V_{DRM}	1600	V
Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$)	V_{RRM}	1600	V
RMS on-state current ($T_c \leqslant 92^\circ\text{C}$)	$I_{T(RMS)}$	60	A
Non repetitive surge peak on-state current (full cycle , $t_p=20\text{ms}$, $T_j=25^\circ\text{C}$)	I_{TSM}	600	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6\text{ms}$, $T_j=25^\circ\text{C}$)		660	
I^2t value for fusing ($t_p=10\text{ms}$, $T_j=25^\circ\text{C}$)	I^2t	1800	A^2s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100\text{Hz}$, $T_j=125^\circ\text{C}$)	dI/dt	100	$\text{A}/\mu\text{s}$
Peak gate current ($t_p=20\mu\text{s}$, $T_j=125^\circ\text{C}$)	I_{GM}	8	A
Average gate power dissipation ($T_j=125^\circ\text{C}$)	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	10	W

Peak pulse voltage (T _j =25°C; non-repetitive,off-state;FIG.7)	V _{pp}	1.1	kV
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ELECTRICAL CHARACTERISTICS(T_j=25°C unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I _{GT}	V _D =12V R _L =33Ω	I - II -III	MAX.	50	mA
V _{GT}		I - II -III	MAX.	1.3	V
V _{GD}	V _D =V _{DRM} T _j =125°C R _L =3.3KΩ	I - II -III	MIN.	0.2	V
I _L	I _G =1.2I _{GT}	I - III	MAX.	120	mA
		II		120	
I _H	I _T =1A		MAX.	80	mA
dV/dt	V _D =1070V Gate Open T _j =125°C		MIN.	1500	V/μs
(dI/dt)c	(dV/dt)c=20V/μs T _j =125°C		MIN.	28	A/ms
t _{on}	I _G =80mA I _A =400mA I _R =40mA T _j =25°C	TYP.	7	70	μs
t _{off}			70		

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V _{TM}	I _{TM} =80A t _p =380μs	T _j =25°C	1.7	V
V _{TO}	Threshold voltage	T _j =125°C	0.75	V
R _D	Dynamic resistance	T _j =125°C	24	mΩ
I _{DRM}	V _D =V _{DRM} V _R =V _{RRM}	T _j =25°C	15	μA
I _{RRM}		T _j =125°C	10	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th(j-c)}	junction to case (AC)	0.35	°C/W
R _{th(j-a)}	junction to ambient (AC)	45	°C/W

ORDERING INFORMATION

<u>J</u>	<u>ST</u>	<u>60</u>	<u>CS</u>	<u>-1600</u>	<u>BW</u>
JieJie Microelectronics Co., Ltd.					
	Triacs				
		<u>I_{T(RMS)}:60A</u>			
			<u>CS:TO-247S</u>		<u>BW:I_{GT1-3}≤50mA</u>
				<u>1600:V_{DRM}/V_{RRM}≥1600V</u>	

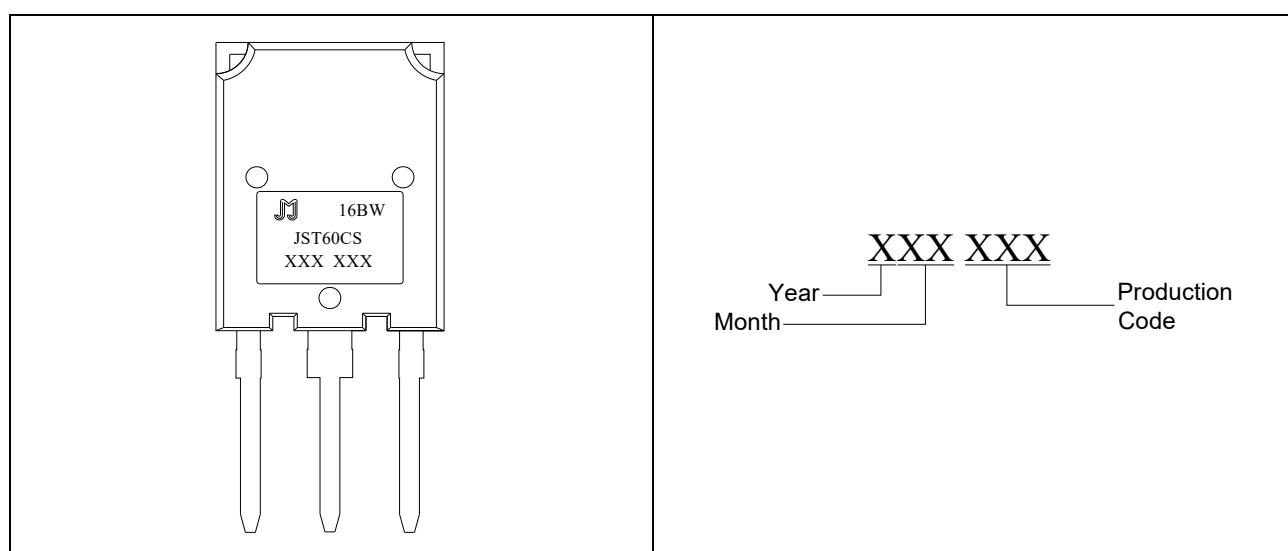
MARKING

FIG.1 Maximum power dissipation versus RMS on-state current

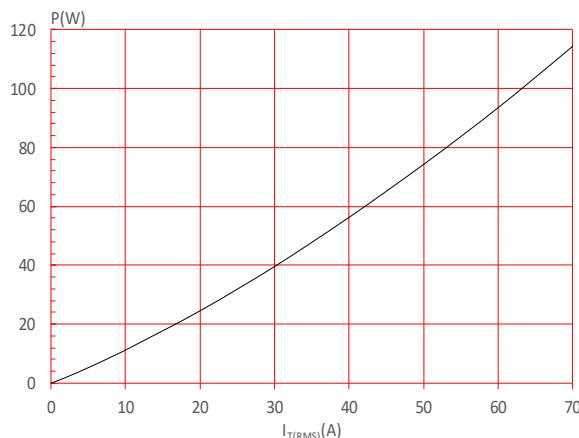


FIG.3: Surge peak on-state current versus number of cycles

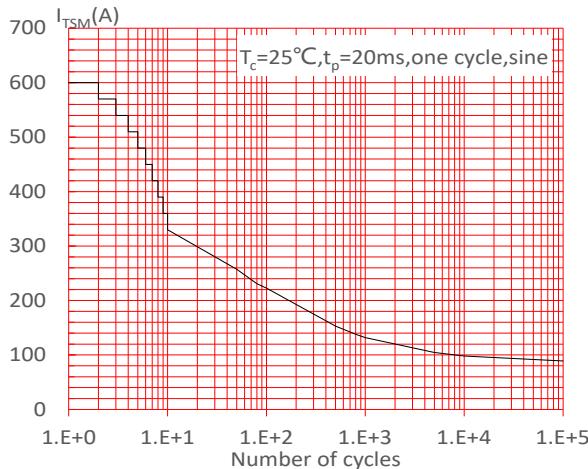


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t ($dI/dt < 100\text{A}/\mu\text{s}$)

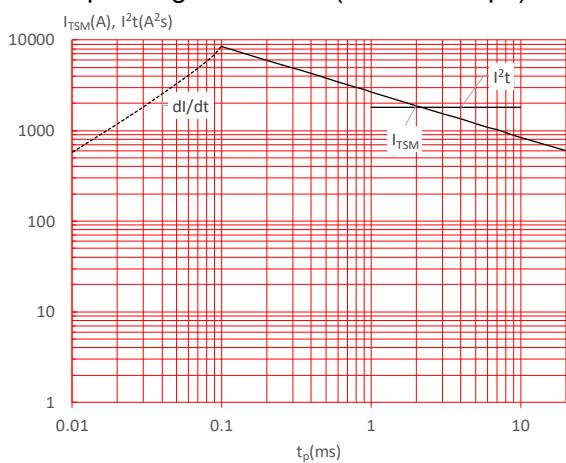


FIG.2: RMS on-state current versus case temperature

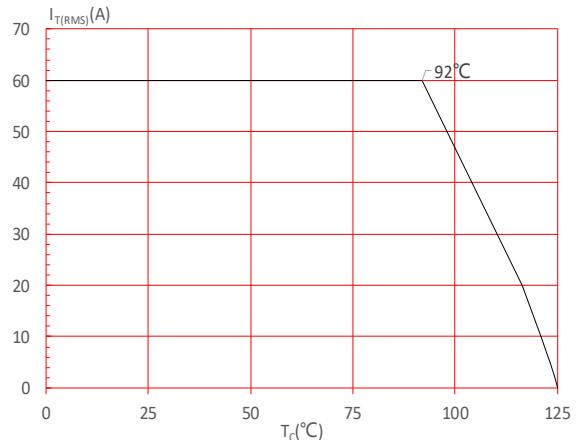


FIG.4: On-state characteristics

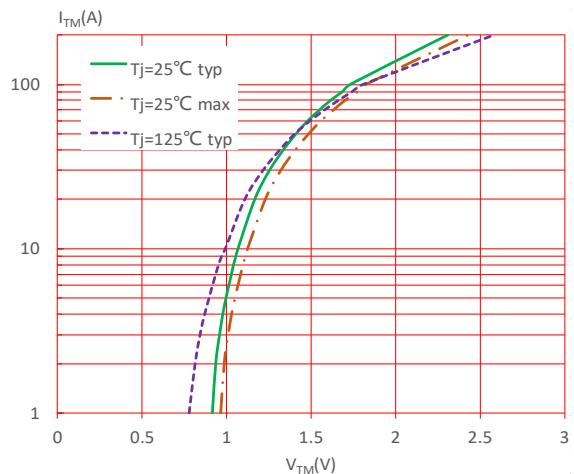


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

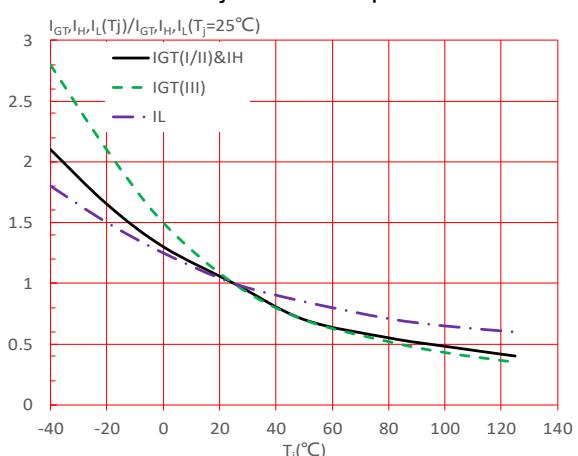
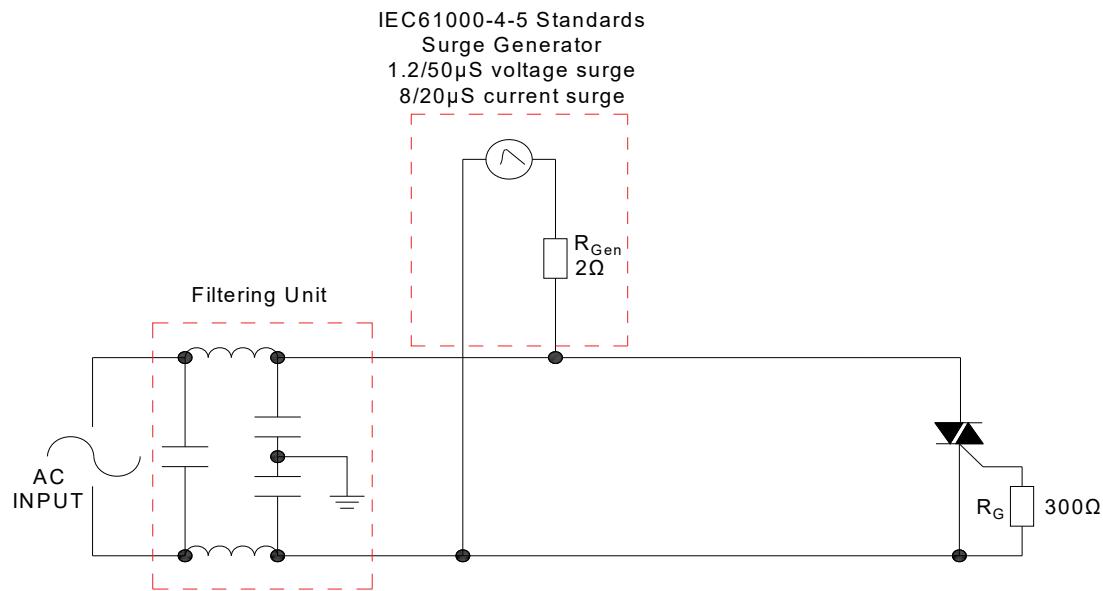


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



SHAPING AND SOLDERING PARAMETERS

Refer to 《Instructions for installation of plastic-sealed in-line power devices》 released by JieJie

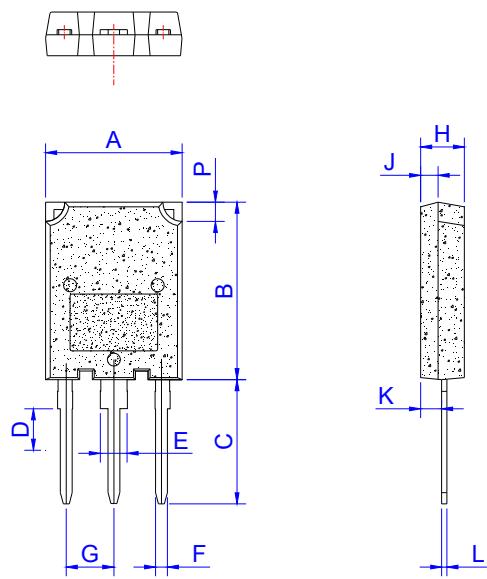
ORDERING INFORMATION

Order code	Voltage $V_{DRM}/V_{RRM}(V)$	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		I -II-III			
JST60CS-1600BW	1600	50	TO-247S	30	Tube

Document Revision History

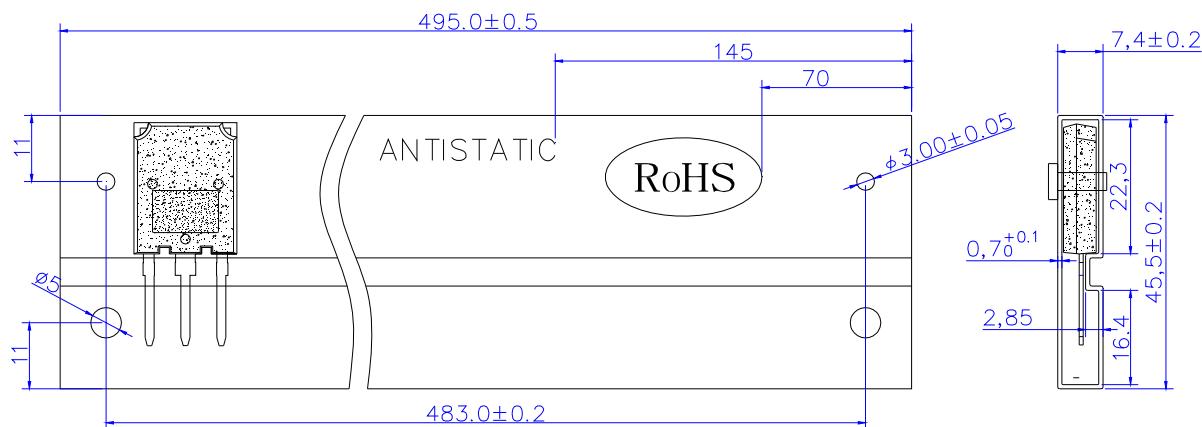
Date	Revision	Changes
Apr.11, 2023	A.1.0	Last updated

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.1		16.1	0.594		0.634
B	19.8		20.8	0.78		0.819
C	13.8		14.8	0.543		0.583
D	3.00		4.00	0.118		0.157
E	2.75		3.35	0.108		0.132
F	1.30		1.50	0.051		0.059
G	5.10		5.80	0.201		0.228
H	4.50		5.50	0.177		0.217
J	1.45		2.15	0.057		0.085
K	1.90		2.80	0.075		0.110
L	0.55		0.80	0.022		0.031
P	2.00		2.40	0.079		0.094

DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-247S	TUBE	30	450	2,250

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